

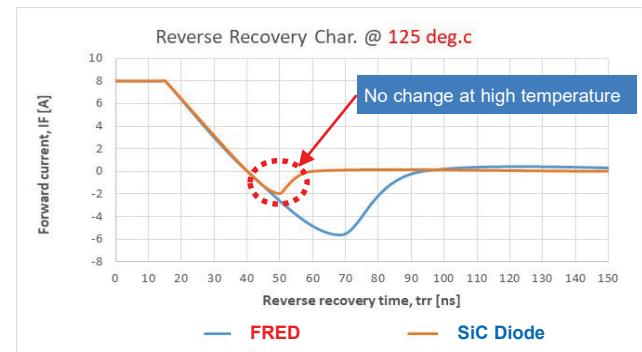
1200V & 650V SiC Diode

Gen 1.5 SiC Diode for the Excellence in Power System Design



► Features

- Zero Reverse Recovery
- Temperature independent switching
- Enhanced surge current capability
- High junction temperature 175°C
- 2 product series for broader choices



Circuit	SiC Diode Device Power Rating	Package
Boost PFC		
Boost Converter	• 650V / 4A -40A	• TO-220AC
Bridgeless PFC	• 1200V / 5A -40A	• TO-252AA
Vienna PFC		• TO-247AD-3LD

► Target Applications



- Server Power
- Telecom Power
- PC Power

- PV Inverter
- ESS / BMS

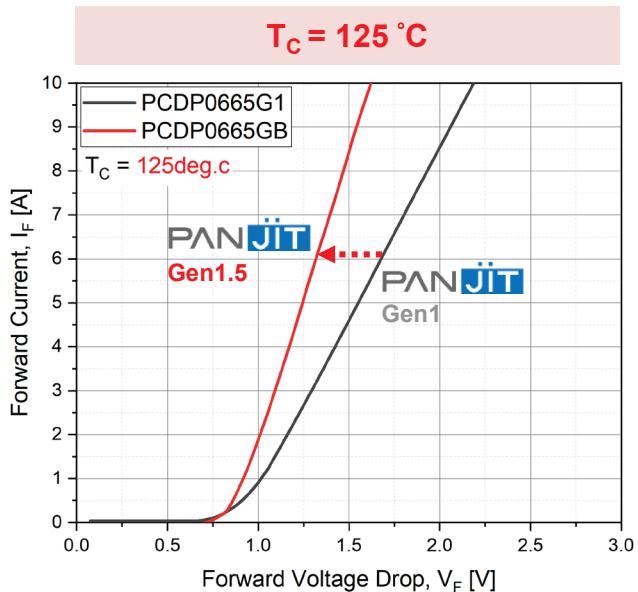
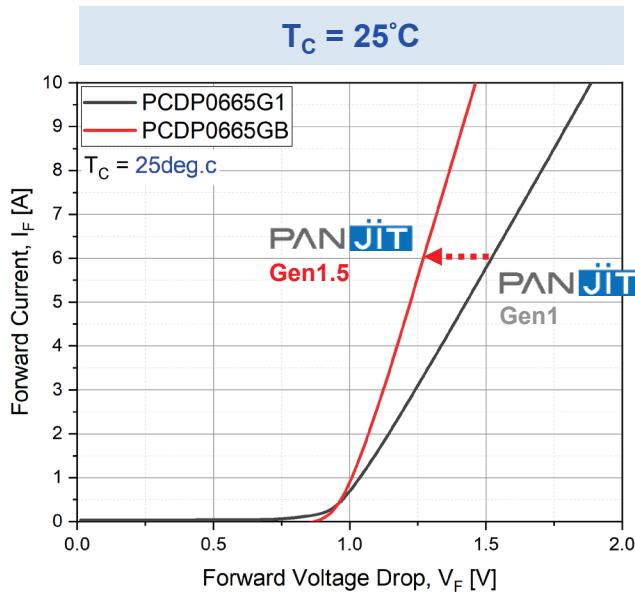
- EV Charging Pile
- UPS
- Industrial Motor

- Home Appliance
- Digital TV



➤ Performance

SiC Diode Gen1.5 Low V_F series (650V / 6A)



➤ Products

Series	BV (V)	I _F (A)	V _F Typ. (V)	TO-220AC	TO-252AA	TO-247AD-3LD
Gen 1.5 Low V_F Series: Low Conduction Loss						
Gen 1.5 Low V _F	650	4	1.3	PCDP0465GB	PCDD0465GB	
		6	1.3	PCDP0665GB	PCDD0665GB	
		8	1.3	PCDP0865GB	PCDD0865GB	
		10	1.3	PCDP1065GB	PCDD1065GB	
		12	1.3	PCDP1265GB		
		16	1.3	PCDP1665GB		
		20	1.3	PCDP2065GB		PCDH2065CCGB
	1200	30	1.3			PCDH3065CCGB
		40	1.3			PCDH4065CCGB
		20	1.4			PCDH20120CCGB
		30	1.4			PCDH30120CCGB
		40	1.4			PCDH40120CCGB
Gen 1.5 Low Q_c Series: Low Switching Loss						
Gen 1.5 Low Q _c	650	8	1.5	PCDP0865GC		
		10	1.5	PCDP1065GC		
		12	1.5	PCDP1265GC		
		16	1.5	PCDP1665GC		
		20	1.5	PCDP2065GC		PCDH2065CCGC
		30	1.5			PCDH3065CCGC
		40	1.5			PCDH4065CCGC